

Complete if known

Application Number: 10/076,858

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First Named Inventor: Steinberg

Group Art Unit: 1775

Examiner Name: Stephen J. Stein

SHEET 1 OF 1 Attorney Docket Number: R&H 03-19

UNITED STATES PATENT DOCUMENTS					
EXAMINER'S INITIALS	CITE NO.	PATENT NUMBER	ISSUE DATE MM-DD-YYYY	FIRST NAMED INVENTOR	
		4810557	03/07/1989	Blonder	
		4837129	06/06/1989	Frisch et al.	
		4863560	09/05/1989	Hawkins	
	·	4904036	02/27/1990	Blonder	
		4938841	07/03/1990	Shahar et al.	
		4957592	09/18/1990	O'Neill	
		5338400	08/16/1994	Jerman	
		5478438	12/26/1995	Nakanishi et al.	
		5479426	12/26/1995	Nakanishi et al.	
		5611006	03/11/1997	Tabuchi	
		5911021	06/08/1999	MacDonald et al.	
		6132107	10/17/2000	Morikawa	
		6187515	02/13/2001	Tran et al.	
		6257772	07/10/2001	Nakanishi et al.	
		6553173	04/22/2003	· Goto	
		6567590	05/20/2003	Okada et al.	
		US 2002/0195417	12/26/2002	Steinberg	
		US 2003/0020130	01/30/2003	Steinberg et al.	
		US 2003/0067049	04/10/2003	Steinberg et al.	
		US 2003/0021572	01/30/2003	Steinberg	

FOREIGN PATENT DOCUMENTS							
EXAMINER'S INITIALS	CITE NO.	DOCUMENT NUMBER	COUNTRY OR REGION	DATE OF PUBLICATION MM-DD-YYYY	FIRST NAMED INVENTOR OR APPLICANT		
	<u> </u>						

OTHER PRIOR ART - NON-PATENT DOCUMENTS				
EXAMINER'S INITIALS	Include name of the author (in Capital Letters), title of the article (when appropriate), title of the article (when ap			
		Nijdam, et al. "Etching of silicon in alkaline solutions: a crtical look at the {111} minimum," MESA		
		Oosterbroek, et al. "New design methodologies in <111> oriented silicon wafers," MESA		
		Suchtelen, et al. "Simulation of Anisotropic Wet-Chemical Etching Using a Physical Model," MESA		

EXAMINER'S	DATE
SIGNATURE	CONSIDERED